







GD65232, GD75232

SLLS206L - MAY 2005 - REVISED AUGUST 2024

GD65232, GD75232 Multiple RS-232 Drivers and Receivers

1 Features

- Single chip with easy interface between UART and serial-port connector of IBM PC/AT and compatibles
- Meet or exceed the requirements of TIA/EIA-232-F and ITU v.28 standards
- Designed to support data rates up to 120kbits
- Pinout compatible with SN75C185 and SN75185
- ESD performance tested per JESD 22: HBM; 1500V, CDM: 500V, MM; 200V

2 Applications

- **Terminals**
- Modems
- Computers
- Wired networking
- Data center and enterprise computing
- Hand-held equipment

3 Description

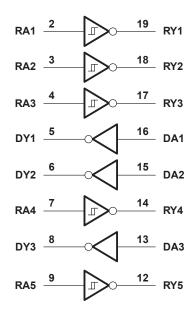
The GD65232 and GD75232 combine three drivers and five receivers from the Texas Instruments tradestandard SN75188 and SN75189 bipolar quadruple drivers and receivers, respectively. The pinout matches the flow-through design of the SN75C185 to decrease the part count, reduce the board space required, and allow easy interconnection of the UART and serial-port connector of an IBM™ PC/AT and compatibles. The bipolar circuits and processing of the GD65232 and GD75232 provide a rugged, lowcost solution for this function at the expense of quiescent power and external passive components relative to the SN75C185.

The GD65232 and GD75232 comply with the requirements of the TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signaling rates up to 20kbits. The switching speeds of these devices are fast enough to support rates up to 120kbits with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be expected unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120kbits, use of TIA/EIA-423-B (ITU V.10) and TIA/EIA-422-B (ITU V.11) standards is recommended.

Package Information

| PART NUMBER | PACKAGE ⁽¹⁾ | PACKAGE SIZE(2) |
|-------------|------------------------|-----------------|
| | SSOP (DB, 20) | 7.2mm x 7.8mm |
| GD65232 | SOIC (DW, 20) | 12.8mm x 10.3mm |
| GD75232 | PDIP (N, 20) | 24.33mm x 9.4mm |
| | TSSOP (PW, 20) | 6.5mm x 6.4mm |

- For more information, see Section 10. (1)
- The package size (length × width) is a nominal value and (2) includes pins, where applicable.



Logic Diagram (positive logic)



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4 Pin Configuration and Functions

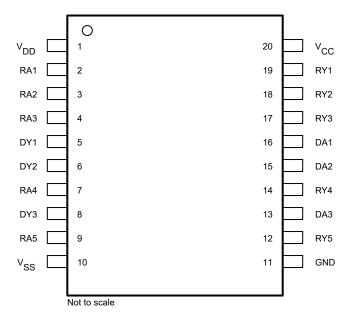


Figure 4-1. DB, DW, N, OR PW Package (Top View)

Table 4-1. Pin Functions

| PIN | | TYPE(1) | DESCRIPTION | |
|-----------------|-----|---------|-----------------------------|--|
| NAME | NO. | ITPE | DESCRIPTION | |
| V_{DD} | 1 | - | Positive RS232 Power Supply | |
| RA1 | 2 | I | RS232 Input | |
| RA2 | 3 | I | RS232 Input | |
| RA3 | 4 | I | RS232 Input | |
| DY1 | 5 | 0 | RS232 Output | |
| DY2 | 6 | 0 | RS232 Output | |
| RA4 | 7 | I | RS232 Input | |
| DY3 | 8 | 0 | RS232 Output | |
| RA5 | 9 | I | RS232 Input | |
| V _{SS} | 10 | - | Negative RS232 Power Supply | |
| GND | 11 | - | Ground | |
| RY5 | 12 | 0 | TTL Output | |
| DA3 | 13 | I | TTL Input | |
| RY4 | 14 | 0 | TTL Output | |
| DA2 | 15 | I | TTL Input | |
| DA1 | 16 | I | TTL Input | |
| RY3 | 17 | 0 | TTL Output | |
| RY2 | 18 | 0 | TTL Output | |
| RY1 | 19 | 0 | TTL Output | |
| V _{CC} | 20 | _ | Device Power Supply for TTL | |

⁽¹⁾ Signal Types: I = Input, O = Output, I/O = Input or Output.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

| | | MIN | MAX | UNIT |
|------------------|--|-----|-----|------|
| V _{CC} | | | 10 | V |
| V _{DD} | Supply voltage (see ⁽²⁾) | | 15 | V |
| V _{SS} | | | -15 | V |
| V | Input voltage range, Driver | -15 | 7 | V |
| V _I | Input voltage range, Receiver | -30 | 30 | V |
| Vo | Driver output voltage range | -15 | 15 | V |
| I _{OL} | Receiver low-level output current | | 20 | mA |
| TJ | Operating virtual junction temperature | | 150 | °C |
| T _{stg} | Storage temperature range | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | NOM | MAX | UNIT |
|-----------------|--|----------|------|-----|------|------|
| VDD | Supply voltage (see (1)) | | 7.5 | 9 | 15 | V |
| VSS | Supply voltage (see (1)) | | -7.5 | -9 | -15 | V |
| V _{CC} | Supply voltage (see (1)) | | 4.5 | 5 | 5.5 | V |
| V _{IH} | High-level input voltage (driver only) | | 1.9 | | | V |
| V _{IL} | Low-level input voltage (driver only) | | | | 0.8 | V |
| ı | I list to the state of the stat | Driver | | | -6 | mΛ |
| I _{OH} | High-level output current | Receiver | | | -0.5 | - mA |
| 1 | Low lovel output ourrent | Driver | | | 6 | m Λ |
| l _{OL} | Low-level output current | Receiver | | | 16 | mA |
| T _A | Operating free air temperature | GD65232 | -40 | | 85 | °C |
| | Operating free-air temperature | GD75232 | 0 | | 70 | |

⁽¹⁾ When powering up the GD65232 and GD75232, the following sequence should be used:

Applying V_{CC} before V_{DD} may allow large currents to flow, causing damage to the device. When powering down the GD65232 and GD75232, the reverse sequence should be used

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⁽²⁾ All voltages are with respect to the network ground terminal

 $[\]bullet \quad \ \ \, V_{SS},\,V_{DD},\,V_{CC},\,I/Os$



5.3 Thermal Information

| THERMAL METRIC(1) | | DB (SSOP) | DW (SOIC) | N (PDIP) | PW (TSSOP) | UNIT |
|-----------------------|--|--------------|--------------|-------------|---------------|------|
| | | 20 PINS | 20 PINS | 20 PINS | 20 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 92.0 | 73.0 | 59.8 | 97.5 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 54.3 | 40.2 | 39.1 | 41.3 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 57.0 | 45.7 | 36.1 | 59.2 | °C/W |
| Ψ ЈТ | Junction-to-top characterization parameter | 14.7 | 12.8 | 18.3 | 4.1 | °C/W |
| Ψ ЈВ | Junction-to-board characterization parameter | 56.3 | 45.0 | 35.7 | 58.6 | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

5.4 Supply Currents over Recommended Operating Free-air Temperature Range

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | | | MIN | MAX | UNIT |
|-----------------|-------------------------------------|---------------------------|---------|----------------------------|------------------------|-----|------|------|
| | | | | V _{DD} = 9V | V _{SS} = -9V | | 15 | |
| | | All inputs at 1.9V | No load | V _{DD} = 12V | V _{SS} = −12V | | 19 | |
| | Supply current from V _{DD} | | | V _{DD} = 15V | V _{SS} = −15V | | 25 | mA |
| I _{DD} | Supply current from V _{DD} | | | V _{DD} = 9V | V _{SS} = -9V | | 4.5 | ilia |
| | All ir | All inputs at 0.8V | No load | V _{DD} = 12V | V _{SS} = −12V | | 5.5 | |
| | | | | V _{DD} = 15V | V _{SS} = −15V | | 9 | |
| | | All inputs at 1.9V | | V _{DD} = 9V | V _{SS} = -9V | | -15 | |
| | | | No load | V _{DD} = 12V | V _{SS} = −12V | | -19 | |
| | Supply ourrant from \/ | | | V _{DD} = 15V | V _{SS} = −15V | | -25 |] mA |
| I _{SS} | Supply current from V _{SS} | | | V _{DD} = 9V | V _{SS} = -9V | | -3.2 | - mA |
| | | All inputs at 0.8V | No load | V _{DD} = 12V | V _{SS} = −12V | | -3.2 | |
| | | | | V _{DD} = 15V | V _{SS} = −15V | | -3.2 | |
| | Supply ourrant from \/ | All inputs at EV | | - 5\/ | GD65232 | | 38 | mΛ |
| I _{CC} | Supply current from V _{CC} | All inputs at 5V No load, | | load, V _{CC} = 5V | | | 30 | - mA |



5.5 Electrical Characteristics, Driver

over operating free-air temperature range V_{DD} = 9V, V_{SS} = -9V, V_{CC} = 5V (unless otherwise noted)

| | PARAMETER | TE | ST CONDITION | ONS | MIN | TYP | MAX | UNIT |
|--------------------|---|-------------------------------------|----------------------|-------------------------------|------|------|-------|------|
| V _{OH} | High-level output voltage | V _{IL} = 0.8V, | $R_L = 3k\Omega$, | See Figure 6-1 | 6 | 7.5 | | V |
| V _{OL} | Low-level output voltage (see (1)) | V _{IH} = 1.9V, | $R_L = 3k\Omega$, | See Figure 6-1 | | -7.5 | -6 | V |
| I _{IH} | High-level input current | V _I = 5V, | See Figure 6-2 | | | | 10 | μA |
| I _{IL} | Low-level input current | V _I = 0, | See Figure 6-2 | | | | -1.6 | mA |
| I _{OS(H)} | High-level short-circuit output current (see ⁽²⁾) | V _{IL} = 0.8V, | V _O = 0, | See Figure | -4.5 | -12 | -19.5 | mA |
| I _{OS(L)} | Low-level short-circuit output current | V _{IH} = 2V, | V _O = 0, | See Figure 6-1 | 4.5 | 12 | 19.5 | mA |
| r _o | Output resistance (see (3)) | V _{CC} = V _{DD} = | V _{SS} = 0, | V _O = −2V to 2V | 300 | | | Ω |

⁽¹⁾ The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only (that is, if -10V is maximum, the typical value is a more negative voltage).

5.6 Switching Characteristics, Driver

over operating free-air temperature range V_{CC} = 5V, V_{DD} = 12V, V_{SS} = -12V, T_A = 25°C (unless otherwise noted)

| | PARAMETER | | TEST CO | NDITIONS | MIN | TYP | MAX | UNIT |
|------------------|--|----------------------------------|--------------------------|--------------------------------------|-----|-----|-----|------|
| t _{PLH} | Propagation delay time, low- to high-level output | $R_L = 3k\Omega$ to $7k\Omega$, | C _L = 15pF, | SeeFigure 6-3 | | 315 | 500 | ns |
| t _{PHL} | Propagation delay time, high- to low-level output | R_L = 3kΩ to 7kΩ, | C _L = 15pF, | See Figure 6-3 | | 75 | 175 | ns |
| t | Transition time, low- to high-level output | $R_L = 3k\Omega$ to $7k\Omega$ | C _L = 15pF, | See Figure 6-3 | | 60 | 100 | ns |
| t _{TLH} | | | C = 2500 pF, | See Figure 6-3 and ⁽¹⁾ | | 1.7 | 2.5 | μs |
| | , , | $R_L = 3k\Omega$ to | C _L = 15pF, | See Figure 6-3 | | 40 | 75 | ns |
| t _{THL} | | | C _L = 2500pF, | See Figure 6-3 and ⁽¹⁾ | | 1.5 | 2.5 | μs |

Measured between ±3V and ±3V points of the output waveform (TIA/EIA-232-F conditions); all unused inputs are tied either high or low.

Product Folder Links: GD65232 GD75232

Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings,

Test conditions are those specified by TIA/EIA-232-F and as listed above



5.7 Electrical Characteristics, Receiver

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST | CONDITIONS | | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-------------------|---|--|------------------------|---------|------|--------------------|------|------|
| \/ | Positive-going input | T _A = 25°C, See Figur | e 6-5 | | 1.75 | 1.9 | 2.3 | V |
| V_{IT+} | threshold voltage | T _A = 0°C to 70°C, Se | e Figure 6-5 | | 1.55 | | 2.3 | V |
| V _{IT} - | Negative-going input threshold voltage | | | 0.75 | 0.97 | 1.25 | V | |
| V _{hys} | Input hysteresis voltage (VIT+ - VIT-) | | | | 0.5 | | | V |
| V | High-level output | | V _{IH} = 0.75 | ίV | 2.6 | 4 | 5 | V |
| V _{OH} | voltage | I _{OH} = −0.5mA Inputs open | | 2.6 | | | V | |
| V _{OL} | Low-level output voltage | I _{OL} = 10mA, V _I = 3V | <u>'</u> | | | 0.2 | 0.45 | V |
| | | V = 25V Soo Figuro | V 05V 0 - 5 5 0 5 | | 3.6 | | 11 | mA |
| I _{IH} | High-level input current | V _I = 25V, See Figure 6-5 GD75232 | | GD75232 | 3.6 | | 8.3 | |
| | | V _I = 3V, See Figure 6-5 | | | 0.43 | | | |
| | | V = 25V Figure 6 5 | | GD65232 | -3.6 | | -11 | mA |
| I _{IL} | Low-level input current | V _I = −25V, Figure 6-5 | | GD75232 | -3.6 | | -8.3 | |
| | | V _I = −3V, See Figure 6-5 | | -0.43 | | | 1 | |
| I _{OS} | Short-circuit output current | See Figure 6-4 | | | -3.4 | -12 | mA | |

⁽¹⁾ All typical values are at T_A = 25°C, V_{CC} = 5 V, V_{DD} = 9 V, and V_{SS} = -9 V.

5.8 Switching Characteristics, Receiver

over operating free-air temperature range V_{CC} = 5V, V_{DD} = 12V, V_{SS} = -12V, T_A = 25°C (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|--|---|-----|-----|-----|------|
| t _{PLH} | Propagation delay time, low- to high-level output | | | 107 | 250 | ns |
| t _{PHL} | Propagation delay time, high- to low-level output | $C_L = 50$ pF, RL = 5 k Ω , See Figure 6-6 | | 42 | 150 | ns |
| t _{TLH} | Transition time, low- to high-level output | | | 175 | 350 | ns |
| t _{THL} | Transition time, high- to low-level output | | | 16 | 60 | ns |
| t _{PLH} | Propagation delay time, low- to high-level output | | | 100 | 160 | ns |
| t _{PHL} | Propagation delay time, high- to low-level output | $C_L = 15$ pF, RL = 1.5k Ω , See | | 60 | 100 | ns |
| t _{TLH} | Transition time, low- to high- level output | Figure 6-6 | | 90 | 175 | ns |
| t _{THL} | Transition time, high- to low-level output | | | 15 | 50 | ns |



5.9 Typical Characteristics Driver

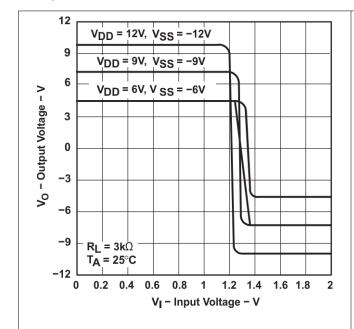


Figure 5-1. Voltage Transfer Characteristics

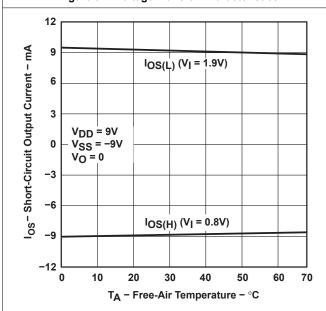


Figure 5-3. Short-Circuit Output Current vs Free-Air Temperature

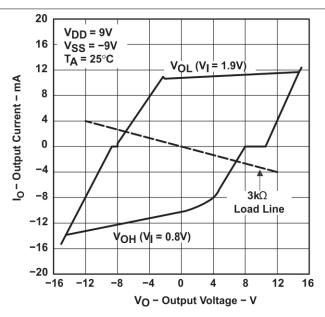


Figure 5-2. Output Current vs Output Voltage

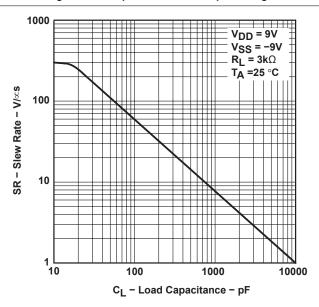


Figure 5-4. Slew Rate vs Load Capacitance



5.10 Typical Characteristics Receiver

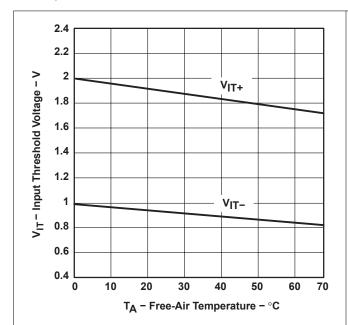


Figure 5-5. Input Threshold Voltage vs Free-Air Temperature

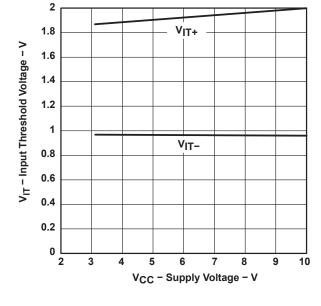
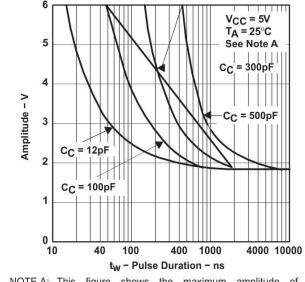


Figure 5-6. Input Threshold Voltage vs Supply Voltage



NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0V, does not cause a change of the output level.



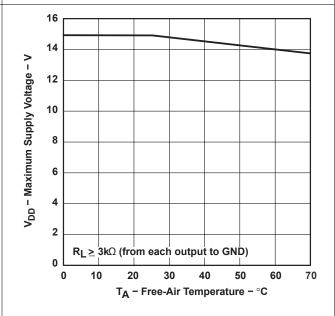


Figure 5-8. Maximum Supply Voltage vs Free-Air Temperature



6 Parameter Measurement Information

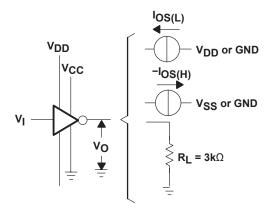


Figure 6-1. Driver Test Circuit for V_{OH} , V_{OL} , $I_{OS(H)}$, and $I_{OS(L)}$

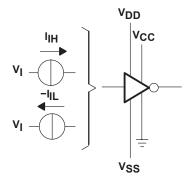
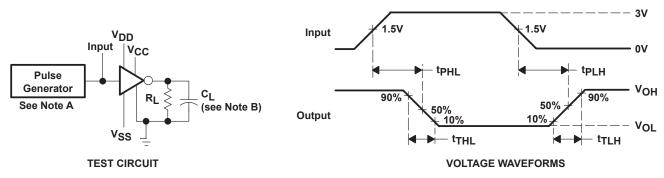


Figure 6-2. Driver Test Circuit for I_{IH} and I_{IL}



- NOTES: A. The pulse generator has the following characteristics: $t_W = 25\mu s$, PRR = 20kHz, $Z_O = 50\Omega$, $t_T = t_f < 50ns$.
 - B. C_L includes probe and jig capacitance.

Figure 6-3. Driver Test Circuit and Voltage Waveforms

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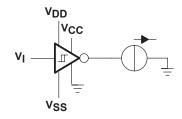


Figure 6-4. Receiver Test Circuit for I_{OS}

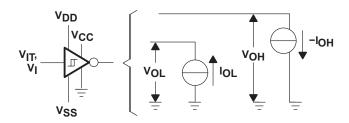
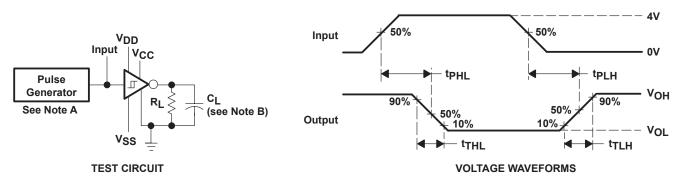


Figure 6-5. Receiver Test Circuit for $V_{\text{IT}},\,V_{\text{OH}},\,\text{and}\,\,V_{\text{OL}}$



NOTES: A. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20kHz, Z $_O$ = 50 Ω , t_T = t_f < 50ns.

B. C_L includes probe and jig capacitance.

Figure 6-6. Receiver Propagation and Transition Times

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

Diodes placed in series with the VDD and VSS leads protect the GD65232 and GD75232 in the fault condition in which the device outputs are shorted to ±15V and the power supplies are at low and provide low-impedance paths to ground, see Figure 7-1.

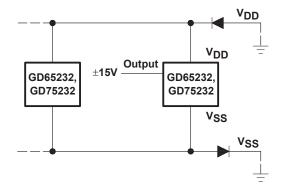


Figure 7-1. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F

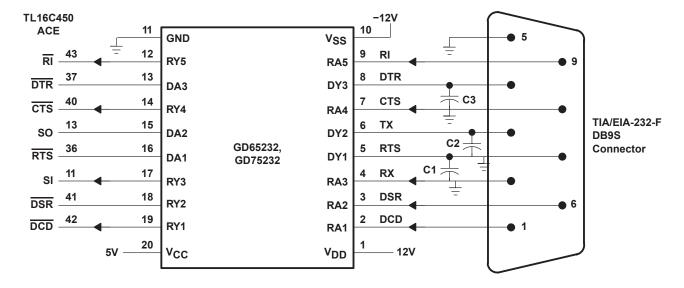


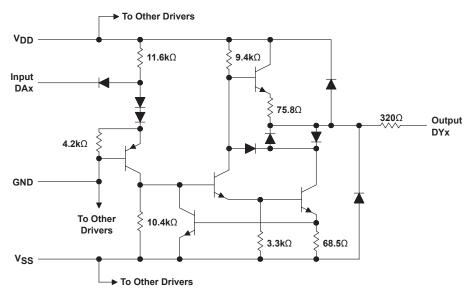
Figure 7-2. Typical Connection

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7.2 Schematic



Resistor values shown are nominal.

Figure 7-3. Schematic (each driver)

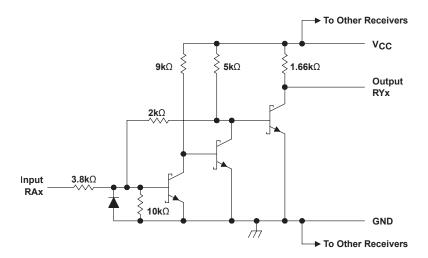


Figure 7-4. Schematic (each receiver)



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| CI | hanges from Revision K (August 2012) to Revision L (August 2024) | Page |
|----|--|------|
| • | Changed the numbering format for tables, figures, and cross-references throughout the document | 1 |
| • | Added the Thermal Information table | 5 |

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: GD65232 GD75232

www.ti.com

8-Jul-2025

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|-----------------|-----------------------|-----------------|-------------------------------|----------------------------|--------------|------------------|
| GD65232DW | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD65232DW.A | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD65232DWR | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD65232DWR.A | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD65232PWR | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD65232PWR.A | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | GD65232 |
| GD75232DBR | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DBR.A | Active | Production | SSOP (DB) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DW | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DW.A | Active | Production | SOIC (DW) 20 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DWR | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DWR.A | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232DWRG4 | Active | Production | SOIC (DW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232N | Active | Production | PDIP (N) 20 | 20 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | GD75232N |
| GD75232N.A | Active | Production | PDIP (N) 20 | 20 TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | GD75232N |
| GD75232PWR | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232PWR.A | Active | Production | TSSOP (PW) 20 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | GD75232 |
| GD75232PWRG4 | Obsolete | Production | TSSOP (PW) 20 | - | - | Call TI | Call TI | 0 to 70 | GD75232 |

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

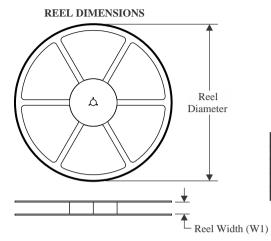
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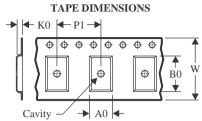
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| GD65232DWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| GD65232PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| GD65232PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| GD75232DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| GD75232DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| GD75232DWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.8 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| GD75232PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| GD75232PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------|--------------|-----------------|------|------|-------------|------------|-------------|
| GD65232DWR | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| GD65232PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| GD65232PWR | TSSOP | PW | 20 | 2000 | 353.0 | 353.0 | 32.0 |
| GD75232DBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| GD75232DBR | SSOP | DB | 20 | 2000 | 353.0 | 353.0 | 32.0 |
| GD75232DWR | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| GD75232PWR | TSSOP | PW | 20 | 2000 | 353.0 | 353.0 | 32.0 |
| GD75232PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |

INSTRUMENTS

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| GD65232DW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| GD65232DW.A | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| GD75232DW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| GD75232DW | DW | SOIC | 20 | 25 | 506.98 | 12.7 | 4826 | 6.6 |
| GD75232DW.A | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| GD75232DW.A | DW | SOIC | 20 | 25 | 506.98 | 12.7 | 4826 | 6.6 |
| GD75232N | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| GD75232N.A | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



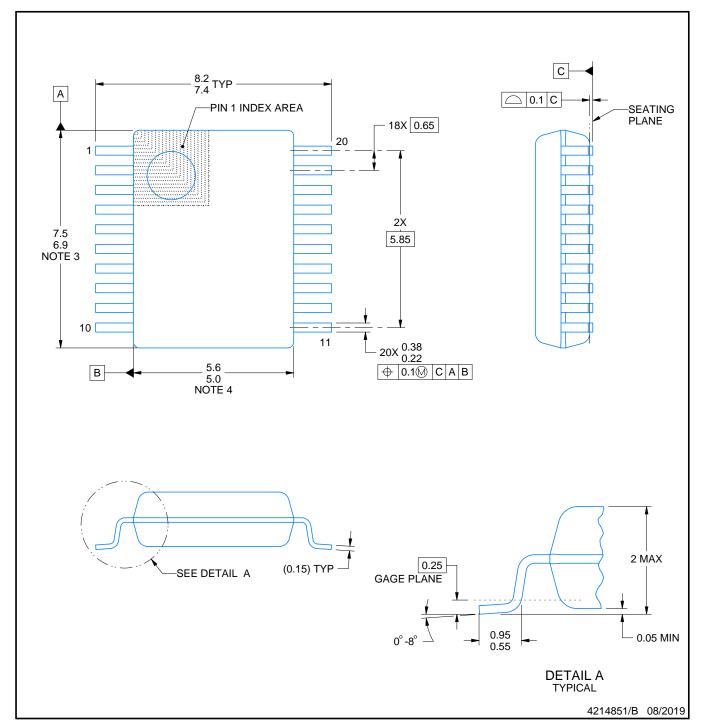


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







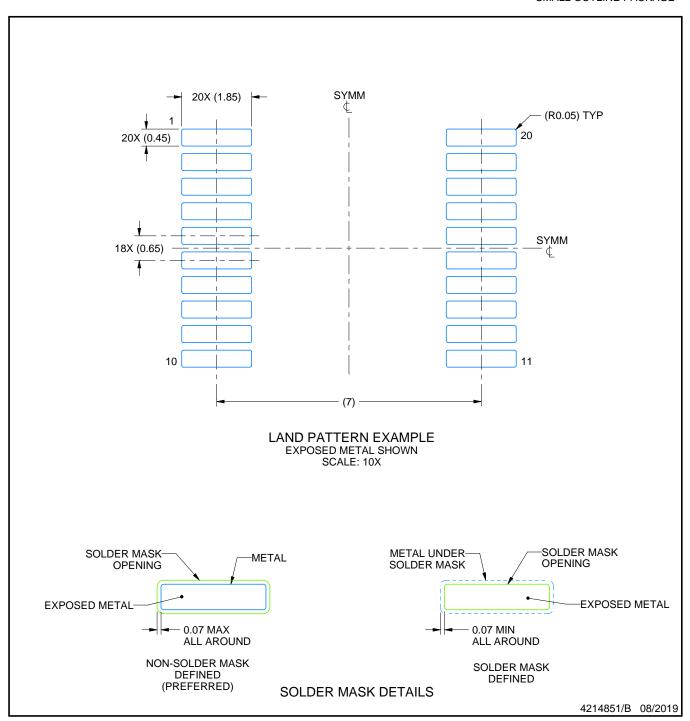
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



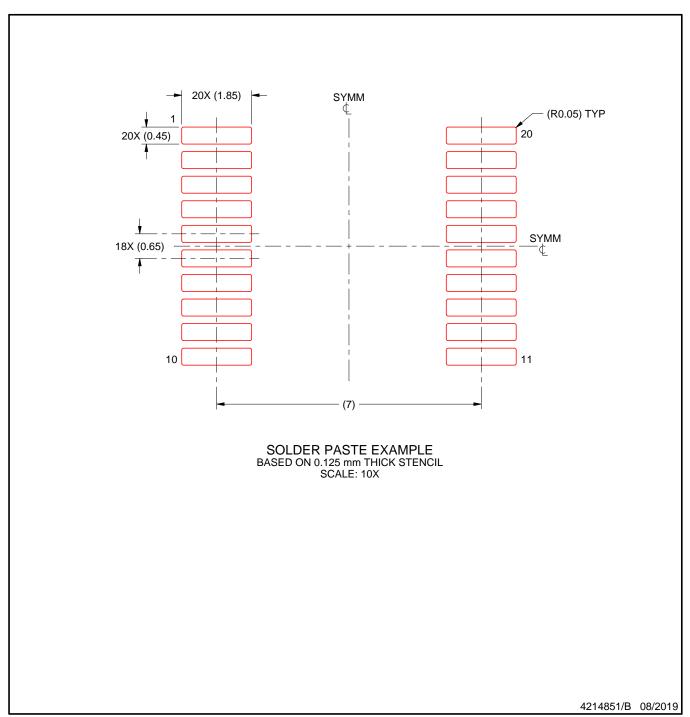


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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